#### Active Doubler 7.5 - 22.5 / 15.0 - 45.0 GHz

#### Features

- +18 dBm Output Power
- -20 dBc Fundamental Leakage
- Lead-Free 3 mm 16-lead QFN Package
- 100% RF, DC and Output Power Testing
- RoHS\* Compliant and 260°C Reflow Compatible

#### Description

The XX1000-QT is a 7.5-22.5/15.0-45.0 GHz SMD active doubler that delivers +18 dBm of output power. The device combines an active doubler with an output buffer amplifier that delivers constant power over a range of input powers. The device has excellent rejection of the fundamental and harmonic products.

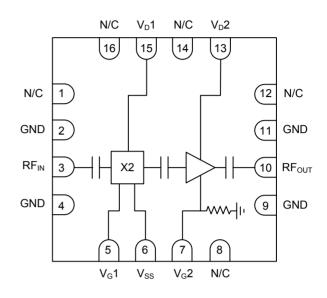
This device uses MACOM's 0.15 GaAs pHEMT device model technology to ensure high reliability and uniformity. The device comes in a low-cost 3 mm QFN surface mount plastic package offering excellent RF and thermal properties and is RoHS compliant.

This device is well suited for Point-to-Point Radio, Microwave, LMDS, SATCOM and VSAT applications.

### **Ordering Information**

Part Number	Package	
XX1000-QT-0G00	bulk quantity	
XX1000-QT-0G0T	tape and reel	
XX1000-QT-EV1	evaluation module	

#### **Functional Block Diagram**



### Pin Configuration<sup>1</sup>

Pin #	Pin Name	Function	
1,8,12,14,16	N/C	Not Connected	
2,4,9,11	GND	Ground	
3	RF <sub>IN</sub>	RF Input	
5	V <sub>G</sub> 1	Gate Voltage 1	
6	V <sub>SS</sub>	Source Voltage	
7	V <sub>G</sub> 2 <sup>1</sup>	Gate Voltage 2	
10	RF <sub>OUT</sub>	RF Output	
13	V <sub>D</sub> 2	Drain Voltage 2	
15	V <sub>D</sub> 1	Drain Voltage 1	
17 <sup>2</sup>	GND	Ground Pad	

 V<sub>G</sub>2 can be used for current regulating V<sub>D</sub>2 or V<sub>G</sub>2 can be set to GND with V<sub>D</sub>2 self-biasing at approximately 140 mA.

2. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

\* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

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#### Electrical Specifications: Input Frequency = 7.5 - 22.5 GHz, $T_A = +25^{\circ}C$

Parameter	Units	Min.	Тур.	Max.
Output Frequency Range	GHz	15.0	-	45.0
Input Return Loss	dB	-	15.0	-
Output Return Loss	dB	-	7.0	-
Saturated Output Power	dBm	-	+18	-
RF Input Power	dBm	-10.0	-	+10.0
Fundamental Leakage	dBc	-	20	-
Third Harmonic Leakage	dBc	-	30	-
Fourth Harmonic Leakage	dBc	-	10	-
Drain Bias Voltage	VDC	-	+5.0	+5.5
Gate Bias Voltage 1	VDC	-0.8	-0.6	-0.4
Gate Bias Voltage 2	VDC	-1.2	0.0	+0.1
Supply Current ( $I_D$ 1,2) ( $V_D$ = 5.0 V, $V_G$ 1 = -0.6 V, $V_G$ 2 = 0.0 V Typ.)	mA	-	220	250
Source Voltage	VDC	-5.5	-5.0	-2.0
Source Current	mA	25	50	60

### Absolute Maximum Ratings<sup>3</sup>

Parameter	Absolute Max.	
Supply Voltage	+6 V	
Supply Voltage	-6 V	
Supply Current	300 mA	
Source Current	60 mA	
Gate Bias Voltage	-0.4 V	
Input Power	+15 dBm	
Storage Temperature	-65°C to +165°C	
Operating Temperature	-55°C to MTTF Table2	
Channel Temperature	MTTF Table2	

 Channel temperature directly affects a device's MTTF. Channel temperature should be kept as low as possible to maximize lifetime.

#### **Handling Procedures**

Please observe the following precautions to avoid damage:

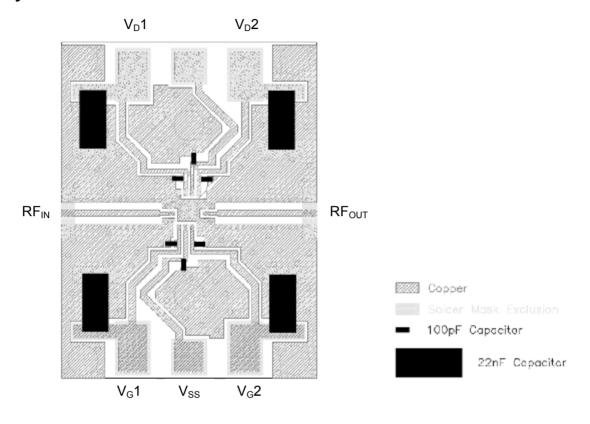
#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 2 devices.

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#### **PCB** Layout



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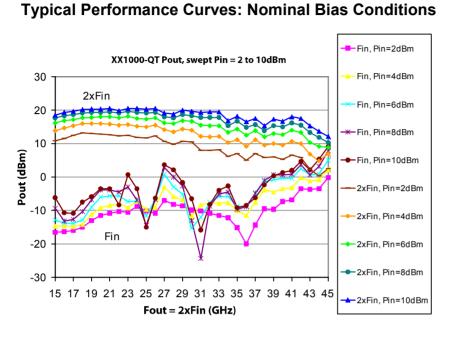


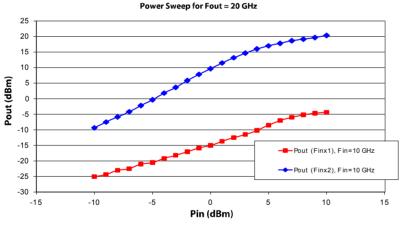
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Measured results taken at room temperature in 40 GHz connectorized test fixture with no de-embedding.

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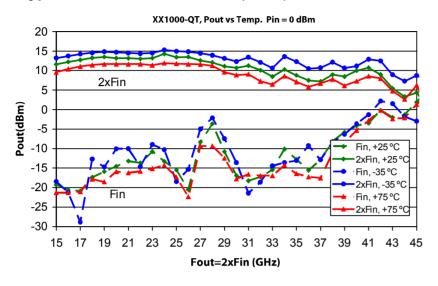
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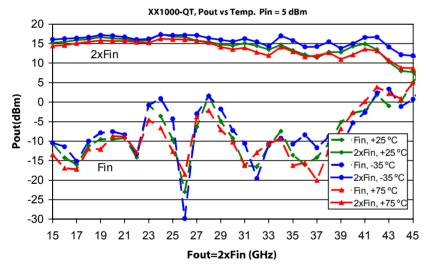


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**Typical Performance Curves (cont.)** 





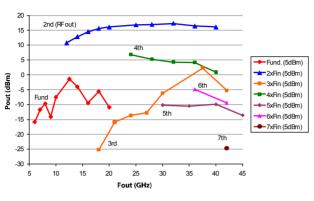
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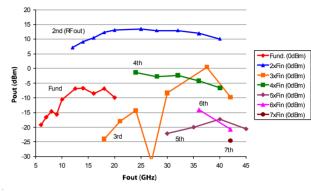
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### **Typical Performance Curves (cont.)**

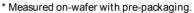


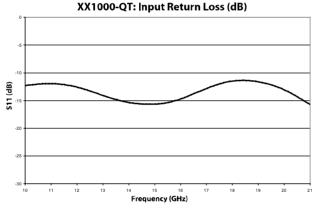
Harmonic Products, Pin = +5 dBm (Fin = 6 - 20 GHz)

\* Measured on-wafer with pre-packaging.



Harmonic Products, Pin = +0 dBm (Fin = 6 - 20 GHz)





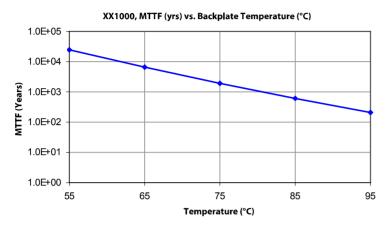
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#### MTTF



MTTF is calculated from accelerated life-time data of single devices and assumes isothermal back-plate.

Bias Conditions:  $V_D 1,2 = 5 V$ ,  $I_D 1,2 = 220 mA$ ,  $V_{SS} = -5 V$ ,  $I_{SS} = 50 mA$ 

#### App Note [1] Biasing -

It is recommended to separately bias each doubler stage with fixed voltages of  $V_D(1,2) = 5$  V,  $V_{SS} = -5$  V and  $V_G1=-0.6$  V. The typical DC currents are  $I_D1 = 80$  mA,  $I_D2 = 140$  mA and  $I_{SS} = 50$  mA.  $V_G2$  can be used for active control biasing of  $V_D2$ , or it can be set to GND and  $V_D2$  will self bias at approximately 140 mA. Maximum output power is achieved with  $V_{SS} = -5$  V and  $I_{SS} = 50$  mA but the device will operate with reduced bias to  $V_{SS} = -2$  V and  $I_{SS} = 25$  mA. It is also recommended to use active biasing on  $V_D2$  with  $V_G2$  to keep the currents constant as the RF power and temperature vary; this gives the most reproducible results. Depending on the supply voltage available and the power dissipation constraints, the bias circuit may be a single transistor or a low power operational amplifier, with a low value resistor in series with the drain supply used to sense the current. The gate of the pHEMT is controlled to maintain correct drain current and thus drain voltage. The typical gate voltage for  $V_G2 = -0.1$  V. Typically the gate is protected with silicon diodes to limit the applied voltage. Also, make sure to sequence the applied voltage to ensure negative gate bias is available before applying the positive drain supply.

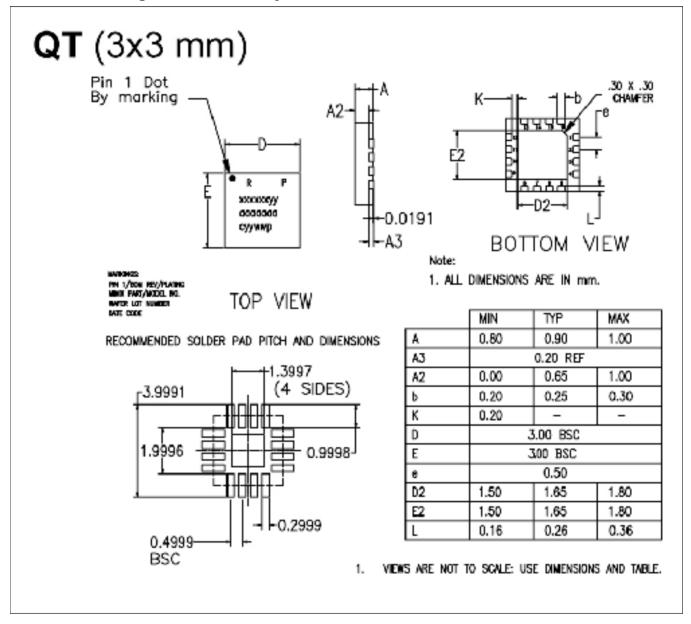
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